■ 8961723 0093188 189 ■ TII3 SN74ABT25241 25-Ω OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

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 State-of-the-Art EPIC-IIB™ BiCMOS Design Significantly Reduces Power Dissipation 	DW OR NT PACKAGE (TOP VIEW)		
 ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0) 	1Y1		
 Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17 	1Y3		
 Typical V_{OLP} (Output Ground Bounce) 1 V at V_{CC} = 5 V, T_A = 25°C 	2Y1 7 18 2A1 GND 8 17 2A2		
• Designed to Facilitate Incident-Wave Switching for Line Impedances of 25 Ω or Greater	2Y2		
 Distributed V_{CC} and GND Pins Minimize Noise Generated by the Simultaneous Switching of Outputs 	2Y4 [12 13] 2OE		
 Bus-Hold Inputs Eliminate the Need for 			

description

External Pullup Resistors

Plastic 300-mil DIPs

 Package Options Include Plastic Small-Outline Packages and Standard

The SN74ABT25241 is a 25- Ω octal buffer and line driver designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented transceivers.

The SN74ABT25241 contains complementary output-enable ($1\overline{OE}$ and 2OE) inputs. When $1\overline{OE}$ is low and 2OE is high, the device transmits data from the A inputs to the Y outputs. When $1\overline{OE}$ and 2OE are high, the outputs are in the high-impedance state. Output-enable $1\overline{OE}$ affects only the 1Y outputs; output-enable 2OE affects only the 2Y outputs.

This buffer/driver is capable of sinking 188 mA of I_{OL} current, which facilitates switching 25- Ω transmission lines on the incident wave. The distributed V_{CC} and GND pins minimize switching noise for more reliable system operation.

Active bus-hold circuitry is provided to hold unused or floating inputs at a valid logic level.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver. OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The SN74ABT25241 is characterized for operation from -40°C to 85°C.

PRODUCT PREVIEW Information concerns products in the formative or design phase of development. Characteristic data and other specifications are design goals. Texas instruments reserves the right to change or discontinue these products without notice.

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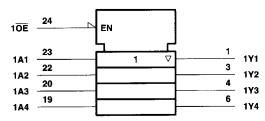
FUNCTION TABLES

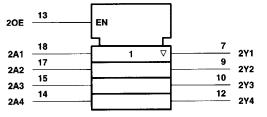
INPUTS		ОИТРИТ
10E	1A	1Y
L	Н	Н
L	L	L
н	X	Z

INPUTS		ОИТРИТ
20E	2A	2Y
Н	Н	Н
Н	L	L
L	Χ	Z

logic symbol†

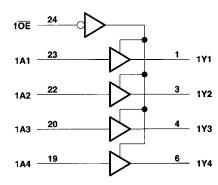
PRODUCT PREVIEW

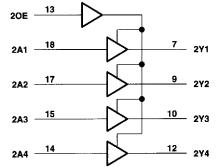




† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the disabled or power-off state, Vo	0.5 V to 5.5 V
Voltage range applied to any output in the high state, VO	
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I _{OK} (V _O < 0)	50 mA
Current into any output in the low state, IO	376 mA
Operating free-air temperature range	40°C to 85°C
Maximum power dissipation at T _A = 55°C (in still air): DW package	
	1.3 W
Storage temperature range	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

recommended operating conditions (see Note 2)

			MIN	MAX	UNIT
Vcc	Supply voltage		4.5	5.5	V
VIH	High-level input voltage		2		٧
٧ _{IL}	Low-level input voltage			8.0	
٧	Input voltage		0	VCC	V
lικ	Input clamp current			-18	mA
ЮН	High-level output current			-80	mA
loL	Low-level output current			188	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10	ns/V
TA	Operating free-air temperature	•	-40	85	°C

NOTE 2: Unused or floating inputs must be held high or low.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
VIK	V _{CC} = 4.5 V,	I _I = -18 mA				-1.2	>	
	V _{CC} = 4.5 V,	IOH = - 3 mA		2.7			v	
VOH	V _{CC} = 5 V,	I _{OH} = – 80 mA		2.4				
	V 45V	I _{OL} = 94 mA				0.55	V	
V _{OL}	V _{CC} = 4.5 V	I _{OL} = 188 mA				0.7 V		
l _l	V _{CC} = 5.5 V,	V _I = V _{CC} or GND				±1	μА	
^I OZH	V _{CC} = 5.5 V,	V _O = 2.7 V				50	μА	
lozL	V _{CC} = 5.5 V,	V _O = 0.5 V				-50	μA	
loff	V _{CC} = 0,	V _I or V _O ≤ 4.5 V				±100	μА	
ICEX	V _{CC} = 5.5 V,	V _O = 5.5 V	Outputs high			50	μ A	
10 [‡]	V _{CC} = 5.5 V,	V _O = 2.5 V		-50		180	mA	
	V _{CC} = 5.5 V, V ₁ = V _{CC} or GND	Outputs open,	Outputs high			500	μА	
lcc			Outputs low			30	mA	
	At = ACC or GIAD		Outputs disabled			500	μA	
ΔICC§	V _{CC} = 5.5 V, Other inputs at V _{CC} or GND	One input at 3.4 V,				1	mA	
Cı	V _{CC} = 5 V,	V _I = V _{CC} or GND					pF	
Со	V _{CC} = 5 V,	Vo = Vcc or GND					pF	

 $[\]dagger$ All typical values are at V_{CC} = 5 V, T_A = 25°C.



[‡] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

^{\$} This is the increase in supply current for each input that is at the specified TTL voltage level rather than VCC or GND.